

# **2SK1304** Silicon N Channel MOS FET

REJ03G0923-0200 (Previous: ADE-208-1262) Rev.2.00 Sep 07, 2005

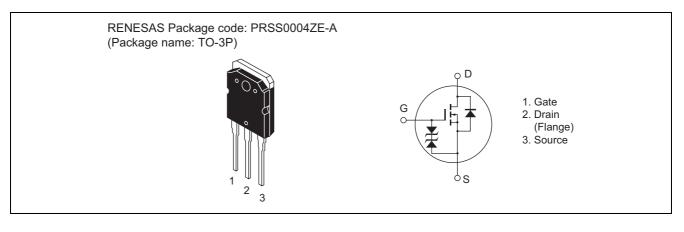
### Application

High speed power switching

### Features

- Low on-resistance
- High speed switching
- Low drive current
- 4 V gate drive device
- Can be driven from 5 V source
- Suitable for motor drive, DC-DC converter, power switch and solenoid drive

### Outline





# **Absolute Maximum Ratings**

$(Ta = 25^{\circ})$
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Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	100	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	ID	40	А
Drain peak current	I <sub>D(pulse)</sub> *1	160	А
Body to drain diode reverse drain current	I <sub>DR</sub>	40	А
Channel dissipation	Pch <sup>*2</sup>	100	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at  $T_C = 25^{\circ}C$ 

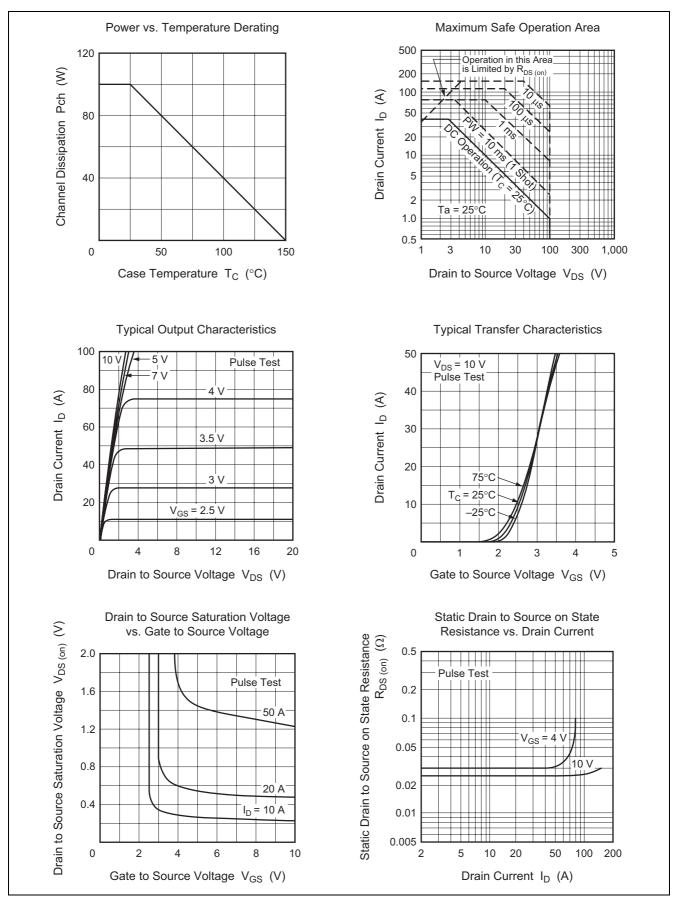
## **Electrical Characteristics**

						$(Ta = 25^{\circ}C)$
ltem	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	100	—	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V <sub>(BR)GSS</sub>	±20	—	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±10	μA	$V_{GS} = \pm 16 \text{ V},  V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	—	250	μA	$V_{DS} = 80 V, V_{GS} = 0$
Gate to source cutoff voltage	V <sub>GS(off)</sub>	1.0	_	2.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state	R <sub>DS(on)</sub>	_	0.025	0.03	Ω	$I_D = 20 \text{ A}, V_{GS} = 10 \text{ V}^{*3}$
resistance			0.03	0.04	Ω	$I_D = 20 \text{ A}, V_{GS} = 4 \text{ V}^{*3}$
Forward transfer admittance	y <sub>fs</sub>	22	35	_	S	$I_D = 20 \text{ A}, V_{DS} = 10 \text{ V}^{*3}$
Input capacitance	Ciss	_	3500	_	pF	$V_{DS} = 10 V, V_{GS} = 0,$
Output capacitance	Coss	_	1400	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	340	_	pF	
Turn-on delay time	t <sub>d(on)</sub>	_	25	_	ns	$I_D = 20 \text{ A}, V_{GS} = 10 \text{ V},$
Rise time	tr	_	170	_	ns	R <sub>L</sub> = 1.5 Ω
Turn-off delay time	t <sub>d(off)</sub>	_	730	_	ns	
Fall time	t <sub>f</sub>	_	300	_	ns	
Body to drain diode forward voltage	$V_{DF}$		1.2	_	V	$I_F = 40 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery	t <sub>rr</sub>		300	_	ns	$I_F = 40 \text{ A}, V_{GS} = 0,$
time						di <sub>F</sub> /dt = 50 A/µs

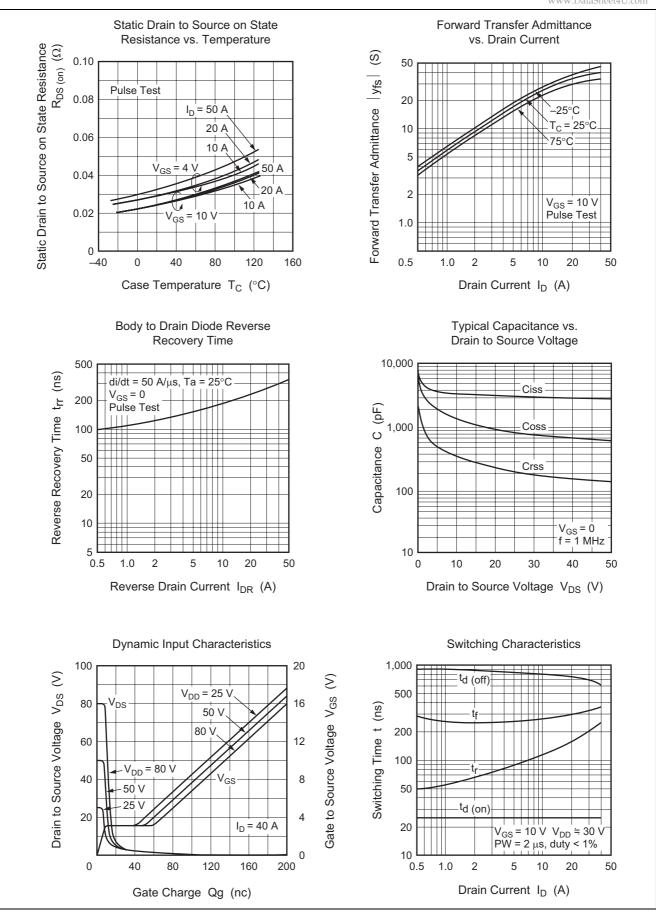
Note: 3. Pulse test

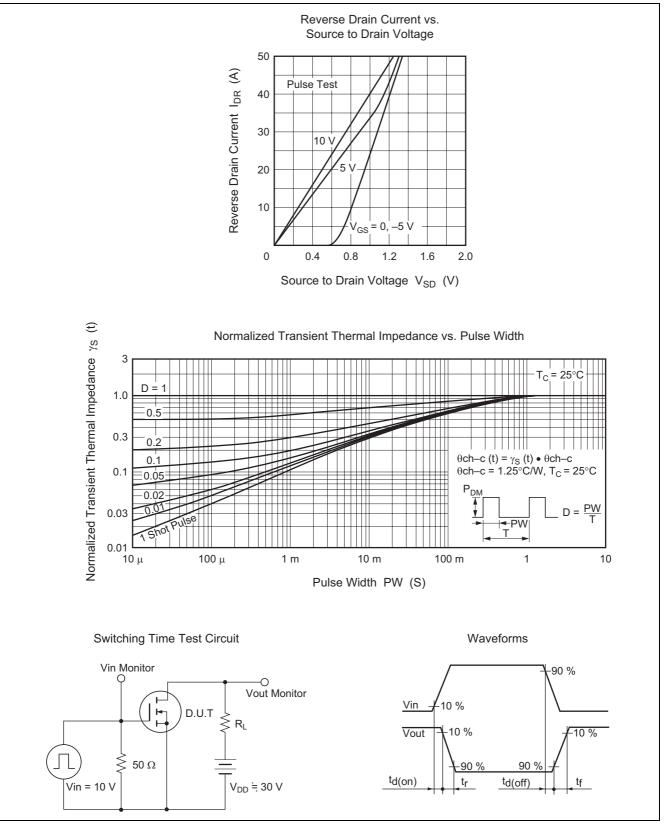


### **Main Characteristics**



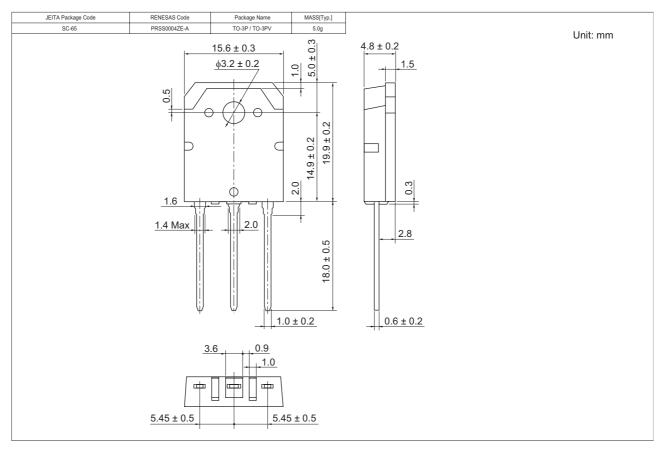








# Package Dimensions



### **Ordering Information**

Part Name	Quantity	Shipping Container
2SK1304-E	30 pcs	Plastic magazine

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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